



IMPORTANT NOTICE

10 December 2015

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors



BYC8D-600

Hyperfast power diode

Rev. 01 — 27 December 2010

Product data sheet

1. Product profile

1.1 General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

1.2 Features and benefits

- Low reverse recovery current and low thermal resistance
- Reduces switching losses in associated MOSFET

1.3 Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

1.4 Quick reference data

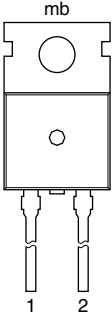
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5 ; T _{mb} ≤ 103 °C; see Figure 1 ; see Figure 2	-	-	8	A
Static characteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C	-	2	2.9	V
		I _F = 8 A; T _j = 150 °C; see Figure 4	-	1.5	1.85	V
Dynamic characteristics						
t _{rr}	reverse recovery time	I _F = 8 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 25 °C; see Figure 5	-	20	-	ns



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	mb	mounting base; connected to cathode		

SOD59 (TO-220AC)

3. Ordering information

Table 3. Ordering information

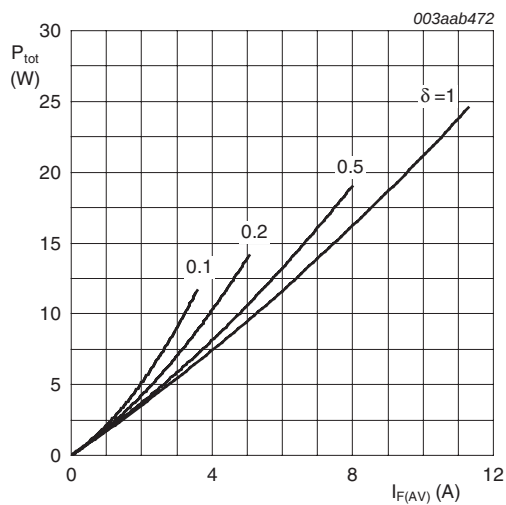
Type number	Package		
	Name	Description	Version
BYC8D-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59

4. Limiting values

Table 4. Limiting values

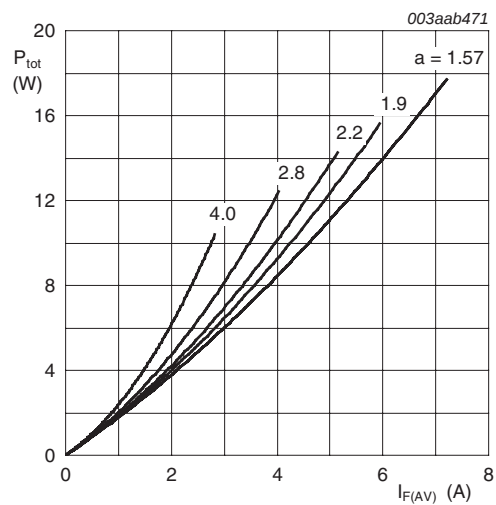
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \leq 103\text{ }^{\circ}\text{C}$; see Figure 1 ; see Figure 2	-	8	A
I_{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 103\text{ }^{\circ}\text{C}$	-	16	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8.3\text{ ms}$; sine-wave pulse; $T_{j(\text{init})} = 150\text{ }^{\circ}\text{C}$	-	60	A
		$t_p = 10\text{ ms}$; sine-wave pulse; $T_{j(\text{init})} = 150\text{ }^{\circ}\text{C}$	-	55	A
T_{stg}	storage temperature		-40	150	$^{\circ}\text{C}$
T_j	junction temperature		-	150	$^{\circ}\text{C}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 3	-	-	2.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

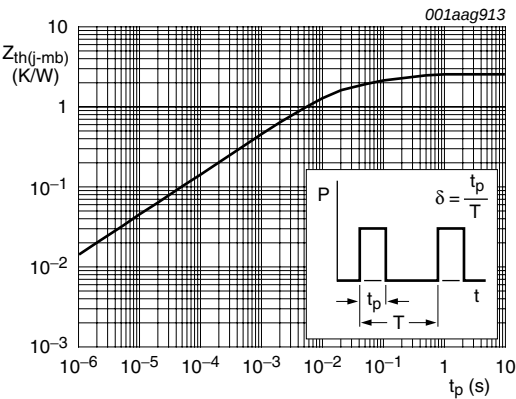
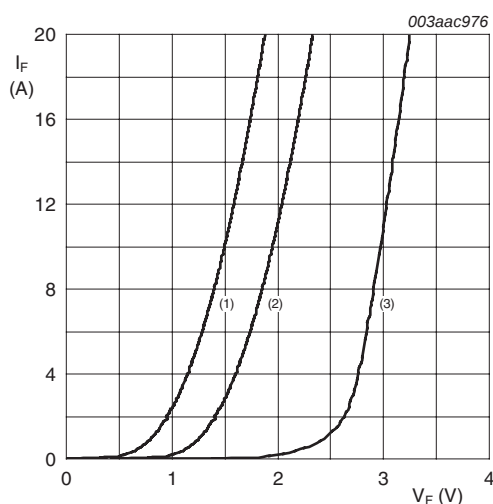


Fig 3. Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C	-	2	2.9	V
		I _F = 8 A; T _j = 150 °C; see Figure 4	-	1.5	1.85	V
I _R	reverse current	V _R = 600 V	-	9	40	μA
		V _R = 500 V; T _j = 100 °C	-	1.1	3	mA
Dynamic characteristics						
Q _r	recovered charge	I _F = 1 A; V _R = 100 V; dI _F /dt = 100 A/μs; T _j = 25 °C	-	13	-	nC
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C	-	30	52	ns
		I _F = 8 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 100 °C	-	32	40	ns
		I _F = 8 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 25 °C; see Figure 5	-	20	-	ns
I _{RM}	peak reverse recovery current	I _F = 8 A; V _R = 400 V; dI _F /dt = 50 A/μs; T _j = 125 °C	-	1.5	5.5	A
		I _F = 8 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 100 °C	-	9.5	12	A
V _{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 100 A/μs; T _j = 25 °C; see Figure 6	-	8	10	V



- (1) $T_j = 150\text{ °C}$; typical values
 (2) $T_j = 150\text{ °C}$; maximum values
 (3) $T_j = 25\text{ °C}$; maximum values

Fig 4. Forward current as a function of forward voltage

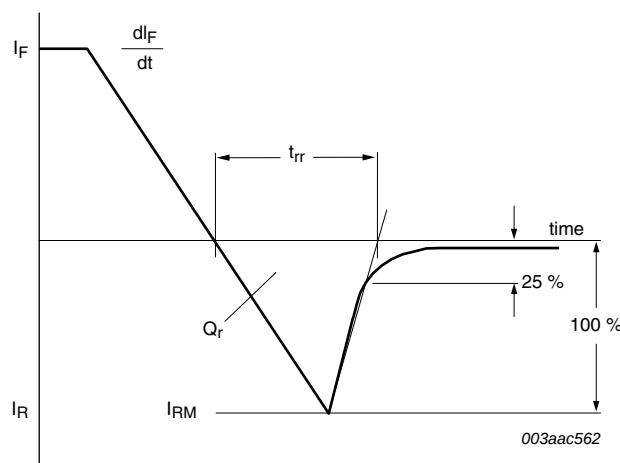


Fig 5. Reverse recovery definitions; ramp recovery

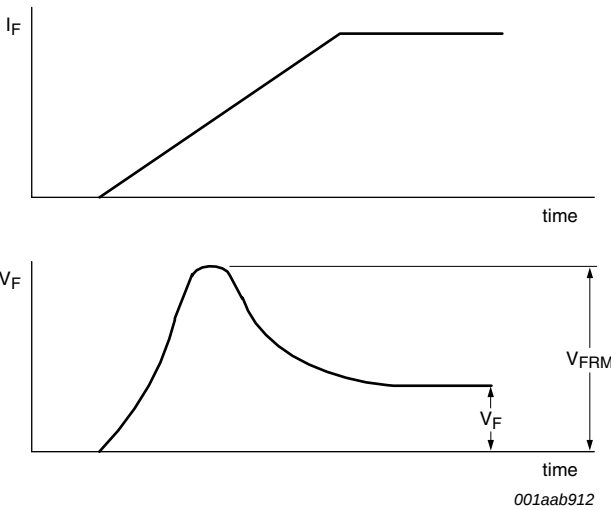


Fig 6. Forward recovery definitions

7. Package outline

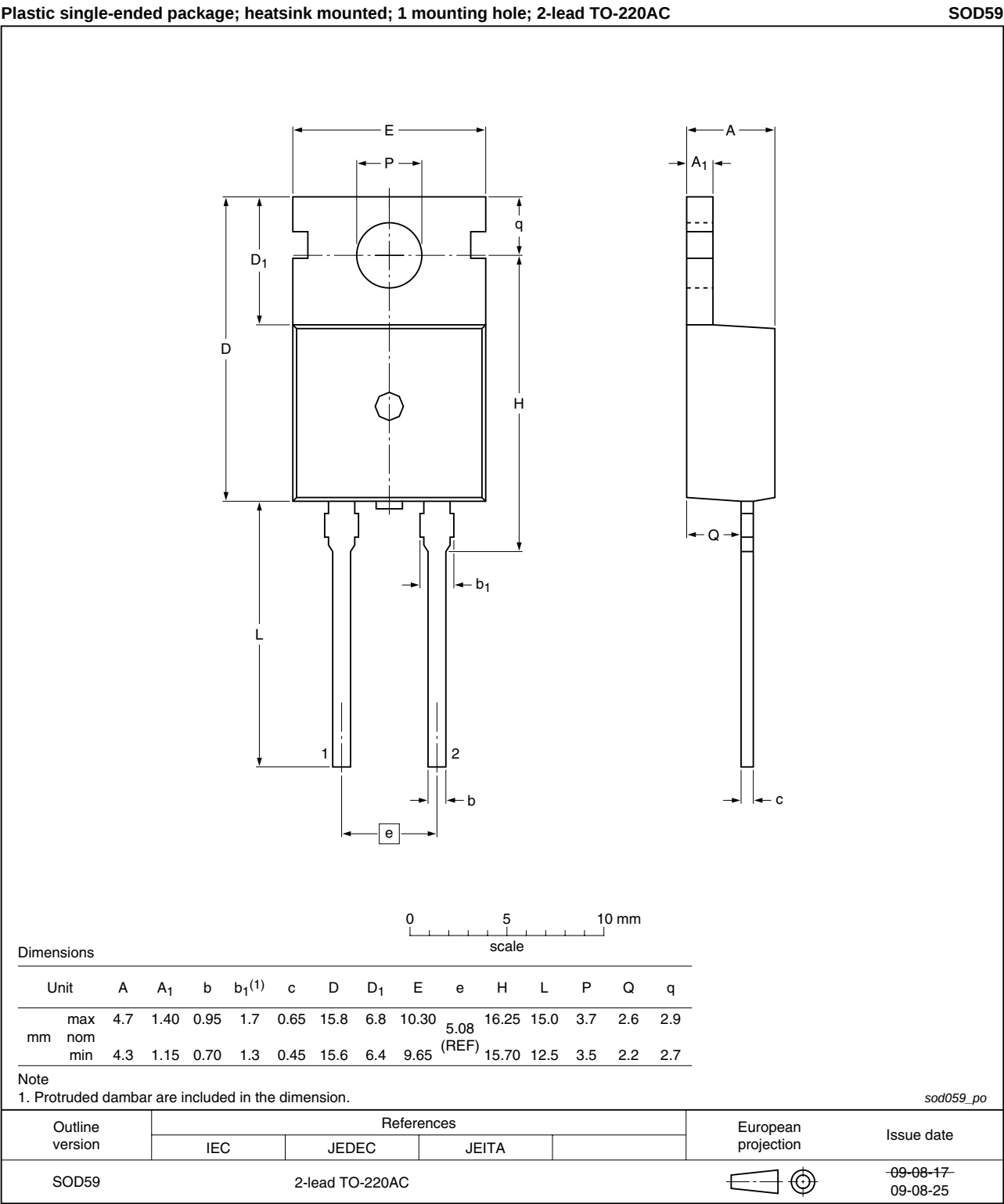


Fig 7. Package outline SOD59 (TO-220AC)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYC8D-600 v.1	20101227	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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11. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	4
6	Characteristics	5
7	Package outline	7
8	Revision history	8
9	Legal information	9
9.1	Data sheet status	9
9.2	Definitions	9
9.3	Disclaimers	9
9.4	Trademarks	10
10	Contact information	10

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